Supporting information:

The effect of Nickel doping on electron and phonon transport in n-type nanostructured thermoelectric material CoSbS Zihang Liu^{a,b}, Huiyuan Geng^c, Jing Shuai^a, Zhengyun Wang^a, Jun Mao^a, Dezhi Wang^a, Qing Jie^a, Wei Cai^b, Jiehe Sui^{a,b,*}and Zhifeng Ren^{a*} ^a Department of Physics and TcSUH, University of Houston, Houston, TX 77204,

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Figure S1. XRD patterns of planes perpendicular and parallel to the hot press direction of $Co_{0.94}Ni_{0.06}SbS$ samples. insert: the schematic diagram of the measured sample.







Figure S2. Temperature dependent thermoelectric performance for $Co_{0.94}Ni_{0.06}SbS$ samples. (a) Electrical resistivity; (b) Seebeck coefficient; (c) Power factor; (d) Total thermal conductivity; (e) ZT values. insert: the schematic diagram of the measured sample.



Figure S3. XRD patterns of hot pressed CoSbS bulk disk and ball-milling CoSbS nanoparticles.



Figure S4. Typical SEM images of undoped CoSbS (a) and Co_{0.94}Ni_{0.06}SbS (b).



Figure S5. (a) Heat capacity and (b) The calculated Lorenz number as a function of temperature for $Co_{1-x}Ni_xSbS$.